



SECTION 9

DUAL-PORT TPU RAM (DPTRAM)

9.1 Introduction

The dual-port RAM module with TPU microcode storage support (DPTRAM) consists of a control register block and a 6-Kbyte array of static RAM, which can be used either as a microcode storage for TPU or as a general-purpose memory.

The DPTRAM module acts as a common memory on the IMB3 and allows the transfer of data to the two TPU3 modules. Therefore, the DPTRAM interface includes an IMB3 bus interface and two TPU3 interfaces. When the RAM is being used in microcode mode, the array is only accessible to the TPU3 via a separate local bus, and not via the IMB3.

The dual-port TPU3 RAM (DPTRAM) is intended to serve as fast, two-clock access, general-purpose RAM memory for the MCU. When used as general-purpose RAM, this module is accessed via the MCU's internal bus.

The DPTRAM module is powered by V_{DDL} in normal operation.

NOTE

The VDDDPTRAM pin does not have circuitry to allow for standby operation and should be connected to V_{DDL} .

The DPTRAM may also be used as the microcode control store for up to two TPU3 modules when placed in a special emulation mode. In this mode the DPTRAM array may only be accessed by either or both of the TPU3 units simultaneously via separate emulation buses, and not via the IMB3. The MC68F375 has only one TPU3.

The DPTRAM contains a multiple input signature calculator (MISC) in order to provide RAM data corruption checking. The MISC reads each RAM address and generates a 32-bit data-dependent signature. This signature can then be checked by the host.

The DPTRAM supports soft defects detection (SDD).

9.2 Features

- Six Kbytes of static RAM
- Only accessible by the CPU if neither TPU3 is in emulation mode
- Low-power stop operation
 - Entered by setting the STOP bit in the DPTMCR
 - Applies only to IMB3 accesses and not to accesses from either TPU3 interface
- TPU microcode mode
 - The DPTRAM array acts as a microcode storage for the TPU module. This provides a means executing TPU code out of DPTRAM instead of program-

ming it in the TPU ROM.

- Includes built in check logic which scans the array contents and calculates the RAM signature
- IMB3 bus interface
- Two TPU3 interface units, only one is used on the MC68F375
- Bytes, half-word or word accessible



9.3 DPTRAM Configuration and Block Diagram

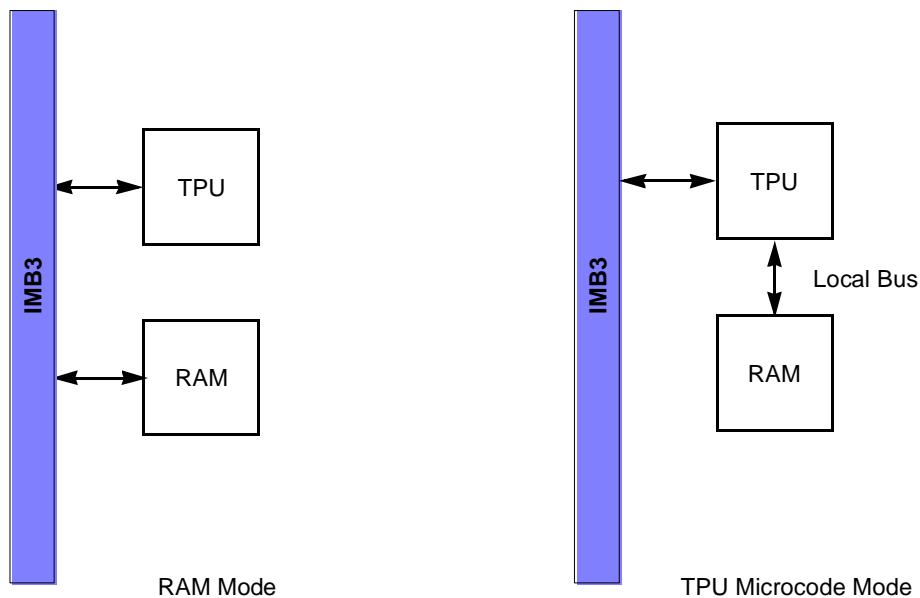


Figure 9-1 DPTRAM Configuration

9.4 Programming Model

The DPTRAM module consists of two separately addressable sections. The first is a set of memory-mapped control and status registers used for configuration (DPTMCR, RAMBAR, MISRH, MISRL, MISCNT) and testing (DPTTCR) of the DPTRAM array. The second section is the array itself.

All DPTRAM module control and status registers are located in supervisor data space. User reads or writes of these will result in a bus error.

When the TPU3 is using the RAM array for microcode control store, none of these control registers have any effect on the operation of the RAM array.

All addresses within the 64-byte control block will respond when accessed properly. Unimplemented addresses will return zeros for read accesses. Likewise, unimplemented bits within registers will return zero when read and will not be affected by write operations.

Table 9-2 DPTMCR Bit Settings



Bit(s)	Name	Description
15	STOP	Low power stop (sleep) mode 0 = DPTRAM clocks running 1 = DPTRAM clocks shut down Only the STOP bit in the DPTMCR may be accessed while the STOP bit is asserted. Accesses to other DPTRAM registers may result in unpredictable behavior. Note also that the STOP bit should be set and cleared independently of the other control bits in this register to guarantee proper operation. Changing the state of other bits while changing the state of the STOP bit may result in unpredictable behavior. Refer to 9.5.4 Stop Operation for more information.
14:11	—	Reserved
10	MISF	Multiple input signature flag. MISF is readable at any time. This flag bit should be polled by the host to determine if the MISC has completed reading the RAM. If MISF is set, the host should read the MISRH and MISRL registers to obtain the RAM signature. 0 = First signature not ready 1 = MISC has read entire RAM. Signature is latched in MISRH and MISRL and is ready to be read.
9	MISEN	Multiple input signature enable. MISEN is readable and writable at any time. The MISC will only operate when this bit is set and the MC68F375 is in TPU3 emulation mode. When enabled, the MISC will continuously cycle through the RAM addresses, reading each and adding the contents to the MISR. In order to save power, the MISC can be disabled by clearing the MISEN bit. 0 = MISC disabled 1 = MISC enabled
8	RASP	Ram area supervisor/user program/data. The RAM array may be placed in supervisor or unrestricted Space. When placed in supervisor space, (RASP = 1), only a supervisor may access the array. If a supervisor program is accessing the array, normal read/write operation will occur. If a user program is attempting to access the array, the access will be ignored and the address may be decoded externally. 0 = Both supervisor and user access to RAM allowed 1 = Supervisor access only to RAM allowed
7:0	—	Reserved

9.4.2 DPTRAM Test Register

DPTTCR — Test Register 0x30 0002

DPTTCR is used only during factory testing of the MCU.

9.4.3 Ram Base Address Register (DPTBAR)

The DPTBAR register is used to specify the 16 MSBs of the starting DPT RAM array location in the memory map.

This register can be written only once after a reset and must be written after the DPRTAM is enabled (DPTMCR STOP = 0b0). This prevents runaway software from inadvertently re-mapping the array. Since the locking mechanism is triggered by the first write after reset, the base address of the array should be written in a single operation. Writing only one half of the register will prevent the other half from being written.

DPTBAR — RAM Array Base Address Register

0xYF F884



MSB 15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	LSB 0
A23	A22	A21	A20	A19	A18	A17	A16	A15	A14	A13	Reserved			RAMDS	

RESET:

0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 1

Table 9-3 DPTBAR Bit Settings

Bit(s)	Name	Description
15:5	A[8:18]	RAM array base address. These bits specify the 11 high-order bits (address lines ADDR[8:18] in little-endian notation) of the 24-bit base address of the RAM array. This allows the array to be placed on a 8-Kbyte boundary anywhere in the memory map. It is the users responsibility not to overlap the RAM array memory map with other modules on the chip.
4:1	—	Reserved. (Bits 11:12 represent A[12:11] in DPTRAM implementation that require them.)
0	RAMDS	RAM disabled. RAMDS is a read-only status bit. The RAM array is disabled after a master reset since the RAMBAR register may be incorrect. When the array is disabled, it will not respond to any addresses on the IMB3. Access to the RAM control register block is not affected when the array is disabled. RAMDS is cleared by the DPTRAM module when a base address is written to the array address field of RAMBAR. RAMDS = 0: RAM enabled RAMDS = 1: RAM disabled

9.4.4 MISR High (MISRH) and MISR Low (MISRL)

The MISRH and MISRL together contain the 32-bit RAM signature calculated by the MISC. These registers are read-only and should be read by the host when the MISF bit in the MCR is set. Note that the naming of the D[31:0] bits represents little-endian bit encoding.

Exiting TPU3 emulation mode results in the reset of both MISRH and MISRL

MISRH — Multiple Input Signature Register High

0xYF F886

MSB 15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	LSB 0
D31	D30	D29	D28	D27	D26	D25	D24	D23	D22	D21	D20	D19	D18	D17	D16

RESET:

0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0

MISRL — Multiple Input Signature Register Low

0xYF F888

MSB 15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	LSB 0
D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0

RESET:

0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0

9.4.5 MISC Counter (MISCNT)

The MISCNT contains the address of the current MISC memory access. This register is read-only. Note that the naming of the A[31:0] bits represents little-endian bit encoding.

Exiting TPU3 emulation mode or clearing the MISEN bit in the DPTMCR results in the reset of this register.

MISCNT — MISC Counter

0xYF F88A

MSB 15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	LSB 0
A12	A11	A10	A9	A8	A7	A6	A5	A4	A3	A2	A1	A0	RESERVED		

RESET:

Last Memory Address

9.5 Operation

The DPTRAM module has several modes of operation. The following sections describe DPTRAM operation in each of these modes.

9.5.1 Normal Operation

In normal operation, the DPTRAM is powered by V_{DDL} and may be accessed via the IMB3 by a bus master.

Read or write accesses of 8, 16, or 32 bits are supported. In normal operation, neither TPU3 accesses the array, nor do they have any effect on the operation of the DPTRAM module.

9.5.2 Standby Operation

The DPTRAM on the MC68F375 does not support standby operation. The VDDDPTRAM should always be powered up and down with VDDL.

9.5.3 Reset Operation

When a synchronous reset occurs, a bus master is allowed to complete the current access. Thus a write bus cycle (byte or half word) that is in progress when a synchronous reset occurs will be completed without error. Once a write already in progress has been completed, further writes to the RAM array are inhibited.

NOTE

A word (32-bit) write will be completed coherently only if the reset occurs during the second (16-bit) write bus cycle. If reset occurs during the first write bus cycle, only the first half word will be written to the RAM array and the second write will not be allowed to occur. In this case, the word data contained in the DPTRAM will not be coherent. The first half word will contain the most significant half of the new word information and the second half word will contain the least significant half of the old word information.



If a reset is generated by an asynchronous reset such as the loss of clocks or software watchdog time-out, the contents of the RAM array are not guaranteed. (Refer to [4.7 Reset](#) for a description of the MC68F375 reset sources, operation, control, and status.)

Reset will also reconfigure some of the fields and bits in the DPTRAM control registers to their default reset state. See the description of the control registers to determine the effect of reset on these registers.

9.5.4 Stop Operation

Setting the STOP control bit in the DPTMCR causes the module to enter its lowest power-consuming state. The DPTMCR can still be written to allow the STOP control bit to be cleared.

In stop mode, the DPTRAM array cannot be read or written. All data in the array is retained. The BIU continues to operate to allow the CPU to access the STOP bit in the DPTMCR. The system clock remains stopped until the STOP bit is cleared or the DPTRAM module is reset.

The STOP bit is initialized to logical zero during reset. Only the STOP bit in the DPTMCR can be accessed while the STOP bit is asserted. Accesses to other DPTRAM registers may result in unpredictable behavior. Note also that the STOP bit should be set and cleared independently of the other control bits in this register to guarantee proper operation. Changing the state of other bits while changing the state of the STOP bit may result in unpredictable behavior.

9.5.5 Freeze Operation

The FREEZE line on the IMB3 has no effect on the DPTRAM module. When the freeze line is set, the DPTRAM module will operate in its current mode of operation. If the DPTRAM module is not disabled, (RAMDS = 0), it may be accessed via the IMB3. If the DPTRAM array is being used by the TPU in emulation mode, the DPTRAM will still be able to be accessed by the TPU microengine.

9.5.6 TPU3 Emulation Mode Operation

To emulate TPU3 time functions, the user stores the microinstructions required for all time functions to be used, in the RAM array. This must be done with the DPTRAM in its normal operating mode and accessible from the IMB3. After the time functions are

stored in the array, the user places one or both of the TPU3 units in emulation mode. The RAM array is then controlled by the TPU3 units and disconnected from the IMB3.



To use the DPTRAM for microcode accesses, set the EMU bit in the corresponding TPU3 module configuration register. Through the auxiliary buses, the TPU3 units can access word instructions simultaneously at a rate of up to 40 MHz.

When the RAM array is being used by either or both of the TPU3 units, all accesses via the IMB3 are disabled. The control registers have no effect on the RAM array. Accesses to the array are ignored, allowing an external RAM to replace the function of the general-purpose RAM array.

The contents of the RAM are validated using a multiple input signature calculator (MISC). MISC reads of the RAM are performed only when the MC68F375 is in emulation mode and the MISC is enabled (MISEN = 1 in the DPTMCR).

Refer to [8.3.6 Emulation Support](#) for more information in TPU3 and DPTRAM operation in emulation mode.

9.6 Multiple Input Signature Calculator (MISC)

The integrity of the RAM data is ensured through the use of a MISC. The RAM data is read in reverse address order and a unique 32-bit signature is generated based on the output of these reads. MISC reads are performed when one of the TPU3 modules does not request back-to-back accesses to the RAM provided that the MISEN bit in the MC68F375 MCR is set.

The MISC generates the DPTRAM signature based on the following polynomial:

$$G(x) = 1 + x + x^2 + x^{22} + x^{31}$$

After the entire RAM has been read and a signature has been calculated, the MISC sets the MISF bit in the MC68F375 MCR. The host should poll this bit and enter a handling routine when the bit is found to be set.

The signature should be then read from the MISRH and MISRL registers and the host determines if it matches the predetermined signature.

The MISRH and MISRL registers are updated each time the MISC completes reading the entire RAM regardless of whether or not the previous signature has been read or not. This ensures that the host reads the most recently generated signature.

The MISC can be disabled by clearing the MISEN bit in the MC68F375 MCR. Note that the reset state of the MC68F375 MISEN is disabled.